

ZXTN4000Z

### **60V NPN LED DRIVING TRANSISTOR IN SOT89**

#### **Features**

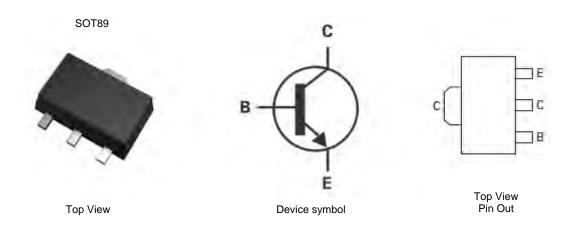
- BV<sub>CEO</sub> > 60V
- Max continuous current I<sub>C</sub> = 1A
- h<sub>FE</sub> > 100 @ I<sub>C</sub> = 150mA, V<sub>CE</sub> = 150mV
- Lead Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT89
- Case material: molded Plastic. "Green" molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.052 grams (Approximate)

### **Applications**

LED TV backlight



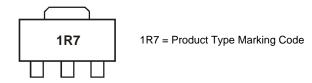
## **Ordering Information** (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN4000ZTA	1S7	7	12	1000 units

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com
- 3. For Packaging Details, go to our website at http://www.diodes.com.

# **Marking Information**





**Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	$V_{EBO}$	7	V
Continuous Collector Current	Ic	1	Α
Peak Pulse Current (Note 4)	I <sub>CM</sub>	3	Α
Base Current	I <sub>B</sub>	500	mA

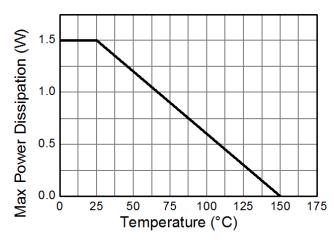
## Thermal Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	1.5	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	83	°C/W
Thermal Resistance, Junction to Leads (Note 6)	R <sub>θJL</sub>	28	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

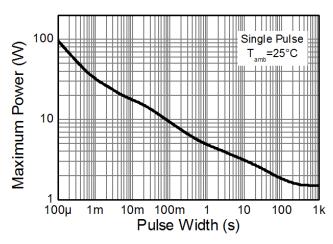
Notes:

- 4. Measured under pulsed conditions. Pulse width = 300µs. Duty cycle ≤ 2%.
- 5. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions
- 6. Thermal resistance from junction to solder-point (at the end of the collector lead).

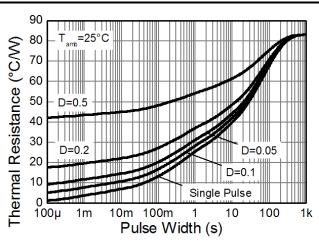
## Thermal Characteristics and Derating information



# **Derating Curve**



**Pulse Power Dissipation** 



**Transient Thermal Impedance** 



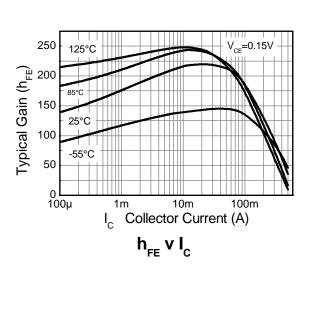
**ZXTN4000Z** 

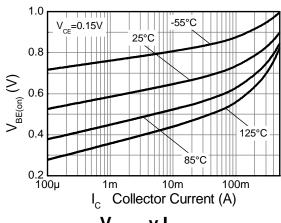
### Electrical Characteristics @TA = 25°C unless otherwise specified

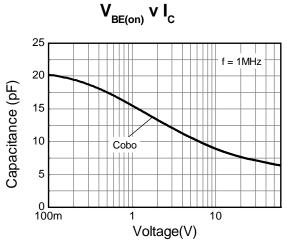
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	60		-	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 7)	BV <sub>CEO</sub>	60		-	V	$I_C = 10mA$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.3	-	V	$I_{E} = 100 \mu A$
Collector Cut-off Current	I <sub>CBO</sub>	-	-	50	nA	$V_{CB} = 60V$
Emitter Cut-off Current	I <sub>EBO</sub>	-	-	50	nA	V <sub>EB</sub> = 7V
Static Forward Current Transfer Ratio (Note 7)	h <sub>FE</sub>	60	-	-	-	$I_C = 85 \text{mA}, V_{CE} = 0.1 \text{V}$
Static Forward Current Transfer Ratio (Note 7)		100	-	-		$I_C = 150 \text{mA}, V_{CE} = 0.15 \text{V}$
Base-Emitter Turn-On Voltage (Note 7)	$V_{BE(on)}$	-	0.76	0.95	V	$I_C = 150 \text{mA}, V_{CE} = 0.15 \text{V}$
Delay Time	$t_{(d)}$	-	300	-	ns	
Rise Time	t <sub>(r)</sub>	-	292	-	ns	$V_{CC} = 48V, I_{C} = 150mA,$
Storage Time	t <sub>(s)</sub>	-	805	-	ns	$-I_{B2} = 1.5 \text{mA}, V_{CE(ON)} = 0.15 \text{V}$
Fall Time	t <sub>(f)</sub>	-	226	-	ns	
Storage Time	t <sub>(s)</sub>	-	25	-	ns	$V_{CC} = 48V, I_{C} = 150mA,$
Fall Time	t <sub>(f)</sub>	-	202	-	ns	$-I_{B2} = 1.5 \text{mA}, V_{CE(ON)} = 4 \text{V}$

Notes: 7. Measured under pulsed conditions. Pulse width = 300µs. Duty cycle ≤ 2%

### Electrical Characteristics @TA = 25°C unless otherwise specified



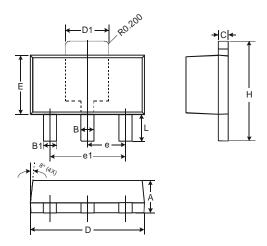




Capacitance v Voltage

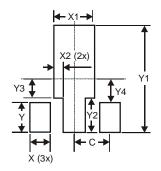


# **Package Outline Dimensions**



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.43		
D	4.40	4.60		
D1	1.52	1.83		
Е	2.29	2.60		
е	1.50 Typ			
e1	3.00 Typ			
Η	3.94	4.25		
L	0.89	1.20		
All Dimensions in mm				

# **Suggested Pad Layout**



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Υ	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500





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